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BIB DATA SHEET

CONFIRMATION NO. 9412

APPLICANTS Erwin A Hijzen, Blanden, BELGIUM; **CONTINUING DATA This application is a 371 of PCT/IB03/06025 12/08/2003 **FOREIGN APPLICATIONS UNITED KINGDOM 0228212.6 12/14/2002 **IF REQUIRED, FOREIGN FILING LICENSE GRANTED **Toraign Priority claimed 30/4 res No 35 USC 119(a-d) conditions mer 30/4 res No 40/400/40046 No 40/40046 No 40/40046	SERIAL NUM	MBER	BER FILING or 371(c)			CLASS G		GROUP ART UNIT			ATTORNEY DOCKET	
APPLICANTS Erwin A Hijzen, Blanden, BELGIUM; "**CONTINUING DATA **********************************	10/538,21							2822		N	NL02 1418 US	
Erwin A Hijzen, Blanden, BELGIUM; **CONTINUING DATA **This application is a 371 of PCT/IB03/06025 12/08/2003 **FOREIGN APPLICATIONS **UNITED KINGDOM 0229212.6 12/14/2002 **IF REQUIRED, FOREIGN FILING LICENSE GRANTED **Foreign Priority claimed		RULE										
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3S USC 119(e-d) conditions met	** IF REQUIRE	ED, FOR	EIGN FILING	LICENS	E GRA	ANTED **						
Acknowledged Examinar's Signature Institute BELGIUM 3 10 2 ADDRESS NXP, B.V. NXP INTELLECTUAL PROPERTY DEPARTMENT M/S41-SJ 1109 MCKAY DRIVE SAN JOSE, CA 95131 UNITED STATES TITLE Method of manufacture of a trench-gate semiconductor device	35 USC 119(a-d) conditions met Yes □ No □ Met after COUNTRY □ DE										INDEPENDENT CLAIMS	
NXP, B.V. NXP INTELLECTUAL PROPERTY DEPARTMENT M/S41-SJ 1109 MCKAY DRIVE SAN JOSE, CA 95131 UNITED STATES TITLE Method of manufacture of a trench-gate semiconductor device								3	10		2	
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Method of manufacture of a trench-gate semiconductor device	NXP INTELLECTUAL PROPERTY DEPARTMENT M/S41-SJ 1109 MCKAY DRIVE SAN JOSE, CA 95131											
☐ All Fees	TITLE											
	Method of	of manuf	acture of a tr	ench-gate	semic	conductor device						
116 Fees (Filipp)		FEES: Authority has been given in Paper No. to charge/credit DEPOSIT ACCOUNT						☐ All Fees				
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FILING FEE								1.17 Fees (Processing Ext. of time)				
RECEIVED No to charge/credit DEPOSIT ACCOUNT 1320 No for following:							1.18 Fees (Issue)					
□ Other							☐ Other					
□ Credit							☐ Credit					